RELIABILITY REPORT
FOR
MAX17126AETM+T
PLASTIC ENCAPSULATED DEVICES

December 9, 2010

MAXIM INTEGRATED PRODUCTS
120 SAN GABRIEL DR.
SUNNYVALE, CA 94086

Approved by
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Quality Assurance
Manager, Reliability Operations
Conclusion

The MAX17126AETM+T successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim’s continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim’s quality and reliability standards.

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I. Device Description

A. General

The MAX17126/MAX17126A generate all the supply rails for thin-film transistor liquid-crystal display (TFT LCD) TV panels operating from a regulated 12V input. They include a step-down and a step-up regulator, a positive and a negative charge pump, an operational amplifier, a high-accuracy high-voltage gamma reference, and a high-voltage switch control block. The MAX17126/MAX17126A can operate from input voltages from 8V to 16.5V and is optimized for an LCD TV panel running directly from 12V supplies. The step-up and step-down switching regulators feature internal power MOSFETs and high-frequency operation allowing the use of small inductors and capacitors, resulting in a compact solution. The step-up regulator provides TFT source driver supply voltage, while the step-down regulator provides the system with logic supply voltage. Both regulators use fixed-frequency current-mode control architectures, providing fast load-transient response and easy compensation. A current-limit function for internal switches and output-fault shutdown protects the step-up and step-down power supplies against fault conditions. The MAX17126/MAX17126A provide soft-start functions to limit inrush current during startup. In addition, the MAX17126/MAX17126A integrate a control block that can drive an external p-channel MOSFET to sequence power to source drivers. The positive and negative charge-pump regulators provide TFT gate-driver supply voltages. Both output voltages can be adjusted with external resistive voltage-dividers. A logic-controlled, high-voltage switch block allows the manipulation of the positive gate-driver supply. The MAX17126/MAX17126A include one high-current operational amplifier designed to drive the LCD back-plane (VCOM). The amplifier features high output current (±200mA), fast slew rate (45V/µs), wide bandwidth (20MHz), and rail-to-rail outputs. Also featured in the MAX17126/MAX17126A is a high-accuracy, high-voltage adjustable reference for gamma correction. The MAX17126/MAX17126A are available in a small (7mm x 7mm), ultra-thin (0.8mm), 48-pin thin QFN package and operate over the -40°C to +85°C temperature range.
II. Manufacturing Information

A. Description/Function: Multi-Output Power Supplies with VCOM Amplifier and High-Voltage Gamma Reference for LCD TVs

B. Process: S45
C. Number of Device Transistors: 21572
D. Fabrication Location: California, Texas or Japan
E. Assembly Location: China and Thailand
F. Date of Initial Production: June 17, 2009

III. Packaging Information

A. Package Type: 48-pin TQFN 7x7
B. Lead Frame: Copper
C. Lead Finish: 100% matte Tin
D. Die Attach: Conductive
E. Bondwire: Au (1.3 mil dia.)
F. Mold Material: Epoxy with silica filler
G. Assembly Diagram: #05-9000-3605
H. Flammability Rating: Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C Level 1
J. Single Layer Theta Ja: 36°C/W
K. Single Layer Theta Jc: 0.8°C/W
L. Multi Layer Theta Ja: 25°C/W
M. Multi Layer Theta Jc: 0.8°C/W

IV. Die Information

A. Dimensions: 110 X 110 mils
B. Passivation: Si3N4/SiO2 (Silicon nitride/ Silicon dioxide)
C. Interconnect: Al/0.5%Cu with Ti/TiN Barrier
D. Backside Metallization: None
E. Minimum Metal Width: Metal1 = 0.5 / Metal2 = 0.6 / Metal3 = 0.6 microns (as drawn)
F. Minimum Metal Spacing: Metal1 = 0.45 / Metal2 = 0.5 / Metal3 = 0.6 microns (as drawn)
G. Bondpad Dimensions: 5 mil. Sq.
H. Isolation Dielectric: SiO2
I. Die Separation Method: Wafer Saw
V. Quality Assurance Information

A. Quality Assurance Contacts:
   Richard Aburano (Manager, Reliability Operations)
   Bryan Preeshl (Vice President of QA)

B. Outgoing Inspection Level:
   0.1% for all electrical parameters guaranteed by the Datasheet.
   0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate:
   < 50 ppm

D. Sampling Plan:
   Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

   The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate ($\lambda$) is calculated as follows:

   $$\lambda = \frac{1}{MTTF} = \frac{1}{192 \times 4340 \times 48 \times 2} = \frac{1.83}{(\text{Chi square value for MTTF upper limit})}$$

   (where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

   $$\lambda = 22.9 \times 10^{-9}$$

   $$\lambda = 22.9 \text{ F.I.T. (60% confidence level @ 25°C)}$$

   The following failure rate represents data collected from Maxim’s reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maxim-ic.com/qa/reliability/monitor. Cumulative monitor data for the S45 Process results in a FIT Rate of 0.49 @ 25°C and 8.49 @ 55°C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing (lot TURYAU002G, D/C 0919)

   The PF58-2 die type has been found to have all pins able to withstand a transient pulse of:

   - ESD-HBM: +/- 2500V per JEDEC JESD22-A114
   - ESD-MM: +/- 180V per JEDEC JESD22-A115

   Latch-Up testing has shown that this device withstands a current of +/- 200mA and overvoltage per JEDEC JESD78, except the LX pin which passes +/- 100mA.
### Table 1
Reliability Evaluation Test Results

<table>
<thead>
<tr>
<th>TEST ITEM</th>
<th>TEST CONDITION</th>
<th>FAILURE IDENTIFICATION</th>
<th>SAMPLE SIZE</th>
<th>NUMBER OF FAILURES</th>
<th>COMMENTS</th>
</tr>
</thead>
<tbody>
<tr>
<td>Static Life Test (Note 1)</td>
<td>Ta = 135°C Biased Time = 192 hrs.</td>
<td>DC Parameters &amp; functionality</td>
<td>48</td>
<td>0</td>
<td>TURZCQ001A, D/C 0906</td>
</tr>
</tbody>
</table>

Note 1: Life Test Data may represent plastic DIP qualification lots.